Vishay Semiconductors



Small Signal Schottky Diode

Features

- For general purpose applications
- This diode features low turn-on voltage
- The devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in a DO-35 case with type designation BAT85
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Applications

Applications where a very low forward voltage is required



Mechanical Data

Case: MiniMELF SOD-80 Weight: approx. 31 mg Cathode band color: black

Packaging codes/options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
BAS85	BAS85-GS18 or BAS85-GS08	-	Tape and Reel

RoHS

COMPLIANT

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Continuous reverse voltage		V _R	30	V	
Forward continuous current		١ _F	200 ¹⁾	mA	
Peak forward current		I _{FM}	300 ¹⁾	mA	
Surge forward current	t _p < 1 s	I _{FSM}	600 ¹⁾	mA	
Power dissipation	T _{amb} = 65 °C	P _{tot}	200 ¹⁾	mW	

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R _{thJA}	430 ¹⁾	K/W
Junction temperature		Tj	125	°C
Storage temperature range		T _{stg}	- 55 to +150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature.

 Document Number 85510
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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	I _R = 10 μA (pulsed)	V _(BR)	30			V
Leakage current	V _R = 25 V	I _R		0.2	2	μA
Forward voltage	Pulse test t _p < 300 μs, I _F = 0.1 mA	V _F			240	mV
	Pulse test $t_p < 300 \ \mu s$, $I_F = 1 \ mA$	V _F			320	mV
	Pulse test t _p < 300 μs, I _F = 10 mA	V _F			400	mV
	Pulse test t _p < 300 μs, I _F = 30 mA	V _F		500		mV
	Pulse test t _p < 300 μs, I _F = 100 mA	V _F			800	mV
Diode capacitance	V _R = 1 V, f = 1 MHz	CD			10	pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $I_{rr} = 1 \text{ mA},$	t _{rr}			5	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

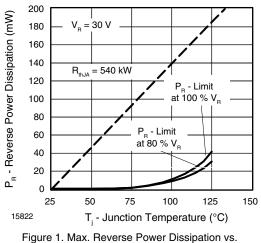
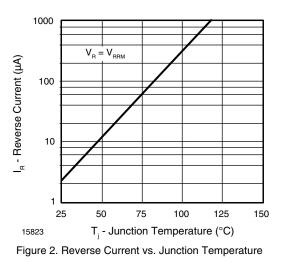
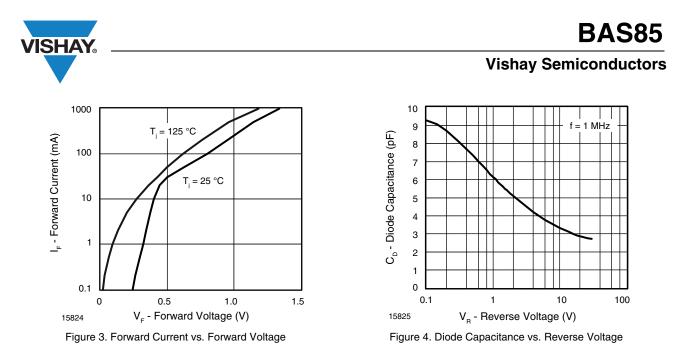
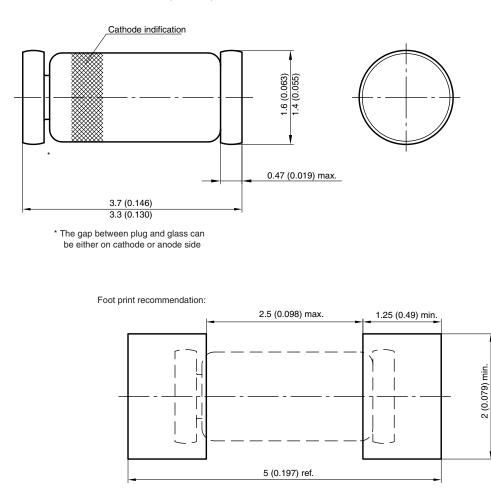


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature





Package Dimensions in millimeters (inches): MiniMELF SOD-80



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070

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